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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
09/497,320	02/03/2000	Ahmad Ghaemmaghami	E0545/1516P	7350	
7	11/19/2002				
Joseph A. Sawyer Jr.			EXAMINER		
Sawyer & Asse PO BOX 5141			DIAZ, J	DIAZ, JOSE R	
Palo Alto, CA 94303			ART UNIT	PAPER NUMBER	
			2815		
			DATE MAILED: 11/19/2002	DATE MAILED: 11/19/2002	

Please find below and/or attached an Office communication concerning this application or proceeding.

•		A will asking No	Applicant(s)				
•		Application No.		,			
		09/497,320	GHAEMMAGHAMI ET A	\L. 			
<i>`</i> ,	Office Action Summary	Examiner	Art Unit				
		José R Díaz	2815				
Period for		nication appears on the cover	sheet with the correspondence address	· 			
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1)⊠	Responsive to communication(s)						
2a)[_	This action is FINAL .	2b)⊠ This action is non-fi		., .			
3)	closed in accordance with the pra	on for allowance except for for otice under <i>Ex parte Quayle</i> ,	ormal matters, prosecution as to the me 1935 C.D. 11, 453 O.G. 213.	erits is			
-	on of Claims	lare pending in the application	an .				
	Claim(s) <u>1,4,5,7,8,11,12 and 14</u> is						
	4a) Of the above claim(s) is/are withdrawn from consideration.						
· ·	Claim(s) is/are allowed.						
	Claim(s) <u>1,4,5,7,8,11,12 and 14</u> is/are rejected.						
•	Claim(s) is/are objected to. Claim(s) are subject to restr	iction and/or election require	ment				
	on Papers	iction and/or cicotion require					
• •	The specification is objected to by t	he Examiner.					
	The drawing(s) filed on is/are		ted to by the Examiner.				
	Applicant may not request that any o	bjection to the drawing(s) be he	ld in abeyance. See 37 CFR 1.85(a).				
11) 🔲 .	The proposed drawing correction fil	ed on is: a)∏ approv	ed b) ☐ disapproved by the Examiner.				
	If approved, corrected drawings are	required in reply to this Office ac	etion.				
12)[The oath or declaration is objected	to by the Examiner.					
Priority ι	ınder 35 U.S.C. §§ 119 and 120						
13)	Acknowledgment is made of a claim	m for foreign priority under 3	5 U.S.C. § 119(a)-(d) or (f).				
a)	☐ All b)☐ Some * c)☐ None of	:					
	1. Certified copies of the priori						
	2. Certified copies of the priority documents have been received in Application No						
	application from the Inte See the attached detailed Office ac	rnational Bureau (PCT Rule tion for a list of the certified o	opies not received.				
			35 U.S.C. § 119(e) (to a provisional app	olication).			
15)	a) The translation of the foreign Acknowledgment is made of a clair	anguage provisional applica n for domestic priority under	tion has been received. 35 U.S.C. §§ 120 and/or 121.				
Attachme		·					
2) Noti	ce of References Cited (PTO-892) ce of Draftsperson's Patent Drawing Reviev mation Disclosure Statement(s) (PTO-1449	4) (PTO-948) 5) (PTO-948) 6) (PTO-948)	5				

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DETAILED ACTION

Continued Examination Under 37 CFR 1.114

A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on November 5, 2002 has been entered.

Claim Rejections - 35 USC § 112

> The following is a quotation of the first paragraph of 35 U.S.C. 112:

The specification shall contain a written description of the invention, and of the manner and process of making and using it, in such full, clear, concise, and exact terms as to enable any person skilled in the art to which it pertains, or with which it is most nearly connected, to make and use the same and shall set forth the best mode contemplated by the inventor of carrying out his invention.

➤ Claims 1, 4-5, 7-8, 11-12 and 14 rejected under 35 U.S.C. 112, first paragraph, as containing subject matter which was not described in the specification in such a way as to reasonably convey to one skilled in the relevant art that the inventor(s), at the time the application was filed, had possession of the claimed invention. The new limitation "wherein the thin photoresist layer is a thickness less than the gate height", as recited in claims 1 and 8 and the Abstract, is not supported by the original Specification. For instance see page 4, lines 22-23 and page 5, lines 11-13 of the Specification, wherein Applicant clearly states that the invention is accomplished by using a thin photoresist mask of 0.1 − 0.2 μm. However, nowhere in the original Specification Applicant states that such a thickness is related to the height of the poly gate. Even if Figure 4 is

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considered as argued by Applicant, one of ordinary skill in the art recognizes that Figure 4 does not support such a new limitation since the thickness is <u>always the same</u> even if additional transistors with <u>different heights</u> are provided on the substrate. For example, consider the height of the poly gate transistor 3, which is less than the height of the poly gate of the transistor 2 and the thickness of the photoresist 402. Thus, the only teaching that Figure 4 provides is that the thickness of the photoresist and the height of the poly gate are not related. Claims 4-5, 11-12 and 14 are rejected due to their dependency on claims 1 and 8, respectively.

Claim Rejections - 35 USC § 103

- ➤ The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of

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35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

➤ Claims 1, 4-5, 7-8, 11-12 and 14 are rejected under 35 U.S.C. 103(a) as being unpatentable over Hori et al. (US Patent No. 5,320,974) in view of Applicant's Specification.

Regarding claims 1, 7-8 and 14, Hori et al. teach a method for providing a halo implant in a semiconductor device (see cols. 1-18) comprising the steps of: providing a thin mask layer (MASK) to the semiconductor device, wherein the thin mask layer (MASK) is a thickness less than a gate height (N+ POLY-SI GATE) and covers a substantial amount of an active area (DRAIN) comprising a source region and a drain region of the semiconductor device; and providing the halo implant (B+) (see Fig. 3). However, Hori et al. fails to teach mask comprising of a DUV photoresist. Applicant acknowledges that is well known in the art to use DUV photoresist to implant the halo region (see page 1, lines 6-12). Therefore, it would have been obvious to one having ordinary skill in the art at the same time the invention was made to modify Hori et al. to include halo mask comprised of a DUV photoresist. The ordinary artisan would have been motivated to modify Hori et al. in the manner described above for at least the purpose of protecting the desired surface of the substrate from the implantation beam.

Regarding claims 4 and 11, Hori et al. teach that a halo implant angle of about 45° (see col.6, lines 60-63).

Regarding claims 5 and 12, Hori et al. teach providing LDD regions (6a and 6b) (see Figs. 1A and 2C).

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Response to Arguments

Applicant's arguments with respect to claims 1, 4-5, 7-8, 11-12, and 14 have been considered but are most in view of the new ground(s) of rejection.

Correspondence

Any inquiry concerning this communication or earlier communications from the examiner should be directed to José R Díaz whose telephone number is (703) 308-6078. The examiner can normally be reached on 9:00-5:00 Monday, Tuesday, Thursday and Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Eddie Lee can be reached on (703) 308-1690. The fax phone numbers for the organization where this application or proceeding is assigned are (703) 308-7722 for regular communications and (703) 746-3891 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

JRD November 16, 2002 SUPERVISORY PATENT EXAMINER TECHNOLOGY CENTER 2800